

# Critical Angle Behavior of Exchange Bias and Coercivity in CoFe/MnIr Bilayers

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**Angular dependence of  $H_{\text{ex}}$  and  $H_c$ , and the critical angle behavior are measured in CoFe/MnIr bilayers annealed at 200°C and 340°C. The interfacial exchange coupling anisotropy and the antiferromagnet anisotropy at  $t_{\text{AF}} < t_{\text{AF}}^c$  are estimated from the best fitting of angular dependence of  $H_{\text{ex}}$  and  $H_c$  using Stoner–Wohlfarth (S–W) model. These results confirm existence of interfacial exchange coupling anisotropy between F and AF layers for  $t_{\text{AF}} < t_{\text{AF}}^c$ . The measured critical angles for  $t_{\text{AF}} > t_{\text{AF}}^c$  as well as for  $t_{\text{AF}} < t_{\text{AF}}^c$  are well explained using S–W model.**

**Index Terms**—Critical AF thickness, critical angle, exchange bias and coercivity, Stoner–Wohlfarth model.

## I. INTRODUCTION

EXCHANGE coupling between ferromagnetic (F) and antiferromagnetic (AF) bilayers has attracted a great deal of attention in recent years because of its applications to the magnetic recording head for high areal density and magnetoresistive random access memory. In view of the great technical interest of these materials, efforts are being put simultaneously on a large scale to utilize the effects of exchange bias in real application systems in one hand and also to carry out extensive experimental and theoretical investigations on the other to explain the mechanism of exchange coupling. As a result, a number of unusual properties were reported such as the asymmetry in the magnetization reversal. In exchange coupled F/AF bilayers, the exchange bias field ( $H_{\text{ex}}$ ) appeared only for a thick enough AF layer whose thickness exceeds a critical AF thickness ( $t_{\text{AF}} > t_{\text{AF}}^c$ ). Besides, the angular dependence of the exchange bias ( $H_{\text{ex}}$ ) and coercive field ( $H_c$ ) have been explained using Stoner–Wohlfarth (S–W) model for  $t_{\text{AF}} > t_{\text{AF}}^c$  under the conditions of uniaxial anisotropy and unidirectional exchange coupling [1]–[3]. The critical angle, which is the offset angle of coercivity with respect to field angle, has also been analyzed for  $t_{\text{AF}} > t_{\text{AF}}^c$  [4], [5]. However, it appears a little attention has been paid toward a study of  $H_{\text{ex}}$  and  $H_c$  for the condition of  $t_{\text{AF}} < t_{\text{AF}}^c$ .

In this work, we measured the  $H_{\text{ex}}$  and  $H_c$  with field angle in the case of  $t_{\text{AF}} > t_{\text{AF}}^c$  as well as  $t_{\text{AF}} < t_{\text{AF}}^c$ . The angular dependence of  $H_{\text{ex}}$  and  $H_c$ , and the critical angle behavior in CoFe/MnIr bilayers were systematically analyzed by using the S–W model.

## II. SAMPLE PREPARATION AND EXPERIMENTAL TECHNIQUES

The Co<sub>70</sub>Fe<sub>30</sub>( $t_{\text{F}} = 100$  nm)/Mn<sub>75</sub>Ir<sub>25</sub> ( $t_{\text{AF}}$  nm) bilayers with  $t_{\text{AF}} = 0, 2, 4, 10$  and  $20$  were deposited onto a Ta 5 nm/Cu

10 nm/NiFe 2 nm/Cu 5 nm buffer layer grown on thermally oxidized Si wafer substrates at room temperature by dc magnetron sputtering method. A magnetic field of 30 Oe was applied during the deposition of bilayers. Post deposition annealing was done on the samples at 200°C and 340°C for 1 h under 1 kOe. The structural analysis was performed by x-ray diffraction and grazing incident x-ray diffraction with CuK $\alpha$  radiation source [6]. The easy axis ( $\theta = 0^\circ$ ) was defined as direction of the applied field during deposition. Magnetization curves with magnetic field angle from  $\theta = 0^\circ$  to  $180^\circ$  were measured using a Magneto-Optic Kerr Effect (MOKE) instrument. The  $H_{\text{ex}}$  and  $H_c$  at each measuring field angle  $\theta$  are determined as a shift of the center and half width of the magnetization curve, respectively.

## III. RESULTS AND DISCUSSION

### A. AF Thickness Dependence of $H_{\text{ex}}$ and $H_c$

Fig. 1 shows the variations in measured  $H_{\text{ex}}$  and  $H_c$  of CoFe/MnIr bilayers with antiferromagnetic layer thickness for both the annealing temperatures. The  $H_{\text{ex}}$  becomes nonzero when  $t_{\text{AF}}$  exceeds about 3 nm and rapidly rises. On the other hand, the  $H_c$  shows a peak response at  $t_{\text{AF}} = 2$  nm. These results indicate that the critical thickness ( $t_{\text{AF}}^c$ ) of MnIr layer to display exchange bias was about 3 nm in these materials, as depicted in Fig. 1(a). The unidirectional exchange coupling constants ( $J = M_s t_{\text{F}} H_{\text{ex}}$ ) are estimated from measured  $H_{\text{ex}}$  values for three samples with different AF thicknesses while considering the  $t_{\text{F}} = 100$  nm and its  $M_s = 1700$  emu/cm<sup>3</sup>. The estimated values of  $J$  for  $t_{\text{AF}} = 4, 10$  and  $20$  nm thicknesses are 0.34, 0.24, and 0.23 erg/cm<sup>2</sup>, respectively, in case of 200°C annealed samples, and 0.46, 0.51, and 0.41 erg/cm<sup>2</sup>, respectively, for 340°C annealed samples.

### B. Angular Dependence of $H_{\text{ex}}$ and $H_c$ in $t_{\text{AF}} < t_{\text{AF}}^c$

The measured angular dependence of  $H_{\text{ex}}$  and  $H_c$  in F/AF bilayers was used for explaining the magnetization reversal behavior, which has also been analyzed theoretically using S–W

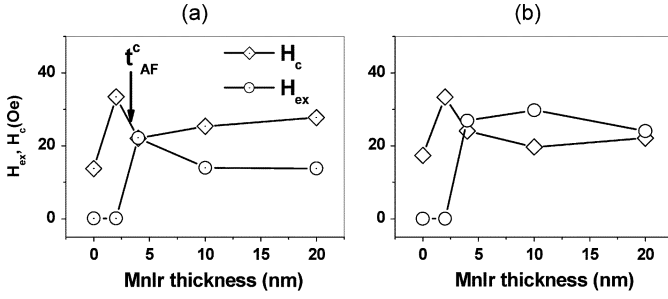


Fig. 1. AF thickness dependence of  $H_{ex}$  and  $H_c$  in CoFe 100 nm/MnIr ( $t_{AF}$  nm) bilayers with  $t_{AF} = 0, 2, 4, 10$  and  $20$  annealed at (a)  $200^\circ\text{C}$  and (b)  $340^\circ\text{C}$ .

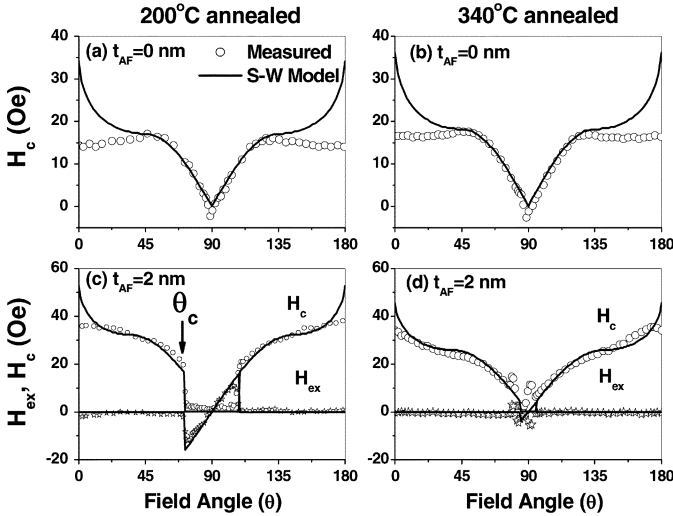


Fig. 2. Angular dependence of  $H_{ex}$  and  $H_c$  in CoFe 100 nm/MnIr ( $t_{AF}$  nm) bilayers with  $t_{AF} = 0$  and  $2$  annealed at (a) and (c)  $200^\circ\text{C}$  and (b) and (d)  $340^\circ\text{C}$ . The lines are calculated using S-W model.

model [1], [2]. Especially, the asymmetric magnetization reversal in Co/IrMn bilayers was theoretically predicted using S-W model [4]. Therefore, qualitative analysis of  $H_{ex}$  and  $H_c$  by S-W model provides scope for understanding the magnetization reversal in F/AF bilayers. The total magnetic energy per unit area of exchange biased F and AF layers with thickness  $t_F$  and  $t_{AF}$ , respectively, can be written as follows:

$$E_T = t_F H M_s \cos(\phi_F - \theta) + t_F K_F \sin^2 \phi_F + t_{AF} K_{AF} \sin^2 \phi + J \cos(\phi_F - \phi_{AF}) \quad (1)$$

where  $K_F$  and  $K_{AF}$  are the uniaxial anisotropy constants for the F and AF layers,  $J$  is the unidirectional exchange coupling energy,  $\theta$  is the magnetic field angle from easy axis, and  $\phi_F$  and  $\phi_{AF}$  are the orientation angles of F magnetization and AF spins, respectively. The angular dependence of  $H_{ex}$  and  $H_c$  are calculated from the minimum condition of the total magnetic energy in (1).

Fig. 2 shows the measured and calculated angular dependence of  $H_{ex}$  and/or  $H_c$  in CoFe/MnIr bilayers for  $t_{AF} = 0$  and  $2$  nm ( $t_{AF} < t_{AF}^c$ ) samples annealed at  $200^\circ\text{C}$  and  $340^\circ\text{C}$ , respectively. In Fig. 2(a) and (b), the significant deviation between measured and calculated  $H_c$  near the easy axis ( $\theta = 0^\circ$ ) may be due to domain nucleation and annihilations processes. However, in the field angles between  $45^\circ < \theta < 135^\circ$ , the measured and calculated  $H_c$  values agreed very well. This agree-

ment could be due to the dominant magnetization rotation behavior, which is related to the anisotropy energy; thus facilitates to obtain  $t_F K_F$  value of the ferromagnetic CoFe layer from the best fitting the angular dependence of  $H_c$  in the angle range of  $45^\circ < \theta < 135^\circ$ . The estimated uniaxial anisotropy constants of  $t_F K_F$  for the  $\text{Co}_{70}\text{Fe}_{30}$  layer, having  $t_F = 100$  nm and  $M_s = 1700$  emu/cm<sup>3</sup>, are  $0.29$  and  $0.31$  erg/cm<sup>2</sup> at  $200^\circ\text{C}$  and  $340^\circ\text{C}$  annealed samples, respectively. These  $t_F K_F$  values are used for the calculation of angular dependence of  $H_{ex}$  and  $H_c$  in CoFe/MnIr bilayers.

Fig. 2(c) and (d) show the angular dependence of  $H_{ex}$  and  $H_c$  for  $t_{AF} = 2$  nm ( $t_{AF} < t_{AF}^c$ ) samples annealed at  $200^\circ\text{C}$  and  $340^\circ\text{C}$ , respectively. The  $H_{ex}$  values at easy axis ( $\theta = 0^\circ$ ) show  $0$  Oe. However, as the field angle increases a negative  $H_{ex}$  appears at a certain angle and correspondingly the  $H_c$  abruptly approaches to zero at this angle, as shown in Fig. 2(c) and (d). Most of the experimental results, reported in the literature, regarding the angular dependence of  $H_{ex}$  and  $H_c$  in exchange biased F/AF bilayers have been focused on  $t_{AF} > t_{AF}^c$  samples. In the present work, our results show a first clear observation of the angular dependence of  $H_{ex}$  and  $H_c$  on  $t_{AF} < t_{AF}^c$  samples. We define the critical angle ( $\theta_c$ ) at the kinks observed in  $H_{ex}$  and at the abrupt decrease in  $H_c$ , as shown in Fig. 2(c). At the critical angle, there observed a transition in the magnetization reversal process from reversible to irreversible behavior [4].

The angle of the ferromagnetic magnetization depends on the direction of the external field due to the Zeeman-term in (1). Due to the coupling between ferromagnetic and antiferromagnetic layers, the direction of the antiferromagnetic magnetization also depends on the external field. Thus, both the anisotropy energy  $t_{AF} K_{AF} \sin^2(\phi_{AF})$  of the AF layer and the coupling energy  $J \cos(\phi_F - \phi_{AF})$  between F/AF bilayers depend on the direction of external field, such that the ratio of these two terms is sometimes smaller than zero (in which case, both layers rotate simultaneously) and sometimes larger than zero (in which case, exchange bias can be observed).

Therefore, the interfacial exchange coupling energy ( $J$ ) and the anisotropy energy of the AF layer ( $t_{AF} K_{AF}$ ) can also be predicted from the best fitting of angular dependence of  $H_{ex}$  and  $H_c$  for  $t_{AF} < t_{AF}^c$ . The estimated values of  $J$  and  $t_{AF} K_{AF}$  for this condition are  $0.51$  and  $0.39$  erg/cm<sup>2</sup>, respectively, for  $200^\circ\text{C}$ -annealed samples, and  $0.35$  and  $0.20$  erg/cm<sup>2</sup>, respectively, for  $340^\circ\text{C}$ -annealed samples. It may be a noteworthy as the annealing temperature increases, the values of  $J$  and  $t_{AF} K_{AF}$  for  $t_{AF} < t_{AF}^c$  decrease, which could be due to inter-diffusion of Mn atoms during annealing at elevated temperature.

Generally, the unidirectional anisotropy  $J$  has been calculated from the measured  $H_{ex}$  in the case of  $t_{AF} > t_{AF}^c$ . However, in the case of  $t_{AF} < t_{AF}^c$ , the  $J$  could not be estimated because of  $H_{ex} = 0$ , as shown in Fig. 1. In this work, we estimated the  $J$  value and  $t_{AF} K_{AF}$  at  $t_{AF} < t_{AF}^c$  through the best curve fitting of angular dependence of the  $H_{ex}$  and  $H_c$ .

### C. Angular Dependence of $H_{ex}$ and $H_c$ in $t_{AF} > t_{AF}^c$

Fig. 3 shows the measured and calculated angular dependence of  $H_{ex}$  and  $H_c$  in CoFe/MnIr (10 nm) bilayers annealed at  $200^\circ\text{C}$  and  $340^\circ\text{C}$ , respectively. In these samples, the  $H_{ex}$  and  $H_c$  with angle shows normal behavior, except the abrupt change of  $H_{ex}$  and  $H_c$  at critical angle ( $\theta_c$ ), as shown in Fig. 3(a). The

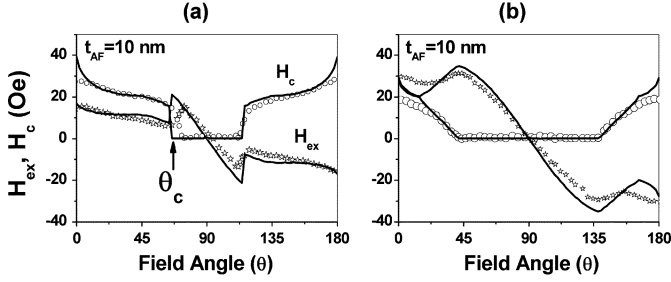


Fig. 3. Angular dependence of  $H_{\text{ex}}$  and  $H_c$  in CoFe 100 nm/MnIr 10 nm bilayers annealed at (a) 200°C and (b) 340°C. The lines are calculated using the S–W model.

kinks in  $H_{\text{ex}}$  and abrupt decrease in  $H_c$  at  $\theta_c$  are dominantly appeared on the conditions of  $H_c > H_{\text{ex}}$ , which is explained by using the S–W model. Xi *et al.* [1] were able to well fit and explained the angular dependence of  $H_{\text{ex}}$  and  $H_c$  of exchange coupled NiFe/CrMnPt bilayers. However, they could not expect the abrupt change of  $H_{\text{ex}}$  and  $H_c$  by using the S–W model in spite of the conditions of  $H_c > H_{\text{ex}}$ .

#### D. Critical Angle Behaviors

The critical angle ( $\theta_c$ ) is one of the transition phenomena between reversible and irreversible magnetization reversal where the coercive field vanishes. Recently, the critical angle was measured at only  $t_{\text{AF}} > t_{\text{AF}}^c$  samples and analyzed using the geometrical asteroid method such as [4], [5]

$$\theta_c = \tan^{-1} \left( \frac{2t_{\text{F}}K_{\text{F}}}{J} \right). \quad (2)$$

The critical angle at  $t_{\text{AF}} > t_{\text{AF}}^c$  is only dependent on the  $t_{\text{F}}K_{\text{F}}$  and  $J$ . In this work, we measured the critical angles ( $\theta_c$ ) from the angular dependence of  $H_{\text{ex}}$  and  $H_c$ . Also, the  $\theta_c$  are calculated by using the S–W model. The measured  $\theta_c$  are separately compared with calculated one as a function of  $t_{\text{AF}}K_{\text{AF}}/J$  and  $t_{\text{F}}K_{\text{F}}/J$  for each case of  $t_{\text{AF}} < t_{\text{AF}}^c$  and  $t_{\text{AF}} > t_{\text{AF}}^c$ , respectively. This was because the critical angle depends on  $t_{\text{AF}}K_{\text{AF}}/J$  as well as  $t_{\text{F}}K_{\text{F}}/J$  in the case of  $t_{\text{AF}} < t_{\text{AF}}^c$ , whereas it only depends on  $t_{\text{F}}K_{\text{F}}/J$  for the case of  $t_{\text{AF}} > t_{\text{AF}}^c$ . The critical angle is found to decrease with  $t_{\text{AF}}K_{\text{AF}}/J$  at  $t_{\text{AF}} < t_{\text{AF}}^c$ , while it increases with  $t_{\text{F}}K_{\text{F}}/J$  at  $t_{\text{AF}} > t_{\text{AF}}^c$ .

Fig. 4(a) shows the measured critical angles at  $t_{\text{AF}} < t_{\text{AF}}^c$ , which are compared with the calculated ones under the conditions of  $t_{\text{F}}K_{\text{F}}/J = 0.57$  and  $0.9$  for comparison between 200°C and 340°C annealed samples. The calculated critical angle at  $t_{\text{AF}} < t_{\text{AF}}^c$  under the condition of  $t_{\text{F}}K_{\text{F}}/J = 0.0$  however shows the low limit values. The values of  $t_{\text{F}}K_{\text{F}}/J$  are obtained from  $t_{\text{F}}K_{\text{F}}$  and  $J$  values, which are estimated from the best fitting of angular dependence of  $H_{\text{ex}}$  and  $H_c$  in Fig. 2. The critical angle in the samples of  $t_{\text{AF}} < t_{\text{AF}}^c$  can be predicted by using the S–W model. Fig. 4(b) shows the measured and calculated critical angles with  $t_{\text{F}}K_{\text{F}}/J$  at  $t_{\text{AF}} > t_{\text{AF}}^c$ . The measured critical angles at  $t_{\text{AF}} > t_{\text{AF}}^c$  showed

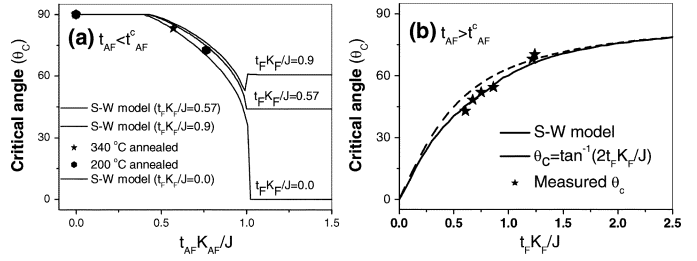


Fig. 4. The critical angle with (a)  $t_{\text{F}}K_{\text{F}}/J$  at  $t_{\text{AF}}K_{\text{AF}} > J$  and (b)  $t_{\text{AF}}K_{\text{AF}}/J$  at  $t_{\text{AF}}K_{\text{AF}} < J$ . The star marks are measured one and the solid lines are calculated one using the S–W model. The dashed line in (b) is calculated by (2).

excellent agreement with calculated ones by using S–W model the (2). The reversible magnetization behavior is generally well explained by the coherent rotation model. Therefore, the critical angle behavior, which is the transition angle from reversible to irreversible magnetization reversal, can also be well predicted by the S–W model.

In summary, we have investigated the angular dependence of  $H_{\text{ex}}$  and  $H_c$ , and the critical angle behavior in CoFe100 nm/MnIr ( $t_{\text{AF}}$  nm) bilayers with  $t_{\text{AF}} = 0, 2, 4, 10$  and  $20$  annealed at 200°C and 340°C. The measured  $H_{\text{ex}}$  and  $H_c$  with angle are compared with calculated ones. The interfacial exchange coupling energy and the antiferromagnet anisotropy at  $t_{\text{AF}} < t_{\text{AF}}^c$  are estimated from the best fitting of angular dependence of  $H_{\text{ex}}$  and  $H_c$ . These results confirm the existence of interfacial exchange coupling anisotropy between F and AF layer at  $t_{\text{AF}} < t_{\text{AF}}^c$ . The measured critical angles both for  $t_{\text{AF}} > t_{\text{AF}}^c$  and  $t_{\text{AF}} < t_{\text{AF}}^c$  are well explained by using the S–W model.

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#### REFERENCES

- [1] H. Xi, M. H. Kryder, and R. M. White, "Study of the angular-dependent exchange coupling between a ferromagnetic and an antiferromagnetic layer," *Appl. Phys. Lett.*, vol. 74, no. 18, pp. 2687–2689, May 1999.
- [2] C. H. Marrows, F. E. Stanley, and B. J. Hickey, "Angular dependence of characteristic fields in spin-valves," *Sens. and Actuators*, vol. 81, pp. 49–52, Apr. 2000.
- [3] T. Ambrose, R. L. Sommer, and C. L. Chien, "Angular dependence of exchange coupling in ferromagnet/antiferromagnet bilayers," *Phys. Rev. B*, vol. 56, no. 1, pp. 83–86, Jul. 1997.
- [4] J. Camarero, J. Sort, A. Hoffmann, J. M. Garcia-Martin, B. Dieny, R. Miranda, and J. Nogues, "Origin of the asymmetric magnetization behavior in exchange-biased systems: Competing anisotropies," *Phys. Rev. Lett.*, vol. 95, pp. 057 204–057 207, Jul. 2005.
- [5] S. H. Chung, A. Hoffmann, and M. Grimsditch, "Interplay between exchange bias and uniaxial anisotropy in ferromagnetic/antiferromagnetic exchange-coupled system," *Phys. Rev. B*, vol. 71, pp. 2 144 301–21 443 010, Jun. 2005.
- [6] M. Tsunoda, T. Sato, and T. Takahashi, "Exchange anisotropy of polycrystalline Mn-Ir/Co-Fe bilayers enlarged by long-time annealing," *Appl. Phys. Lett.*, vol. 84, no. 25, pp. 5222–5225, Jun. 2004.

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